

SEP 16 2005

400 Garden City Plaza – Suite 300
Garden City, New York 11530
(516) 742-4343 - Telephone
(516) 742-4366 – Facsimile
e-mail: intprop@ssmp.com

**SCULLY, SCOTT, MURPHY
& PRESSER****Fax****To:** Examiner Fernando L. Toledo**From:** Leslie S. Szivos

Art Unit: 2823

Fax: 571-273-8300**Pages:** 6 pages including fax cover**Phone:****Date:** 9/16/2005

Re: Hussein I. Hanafi et al.
U.S. Patent Appln. No. 10/659,949
Docket: YOR920020182US2 (15790A)

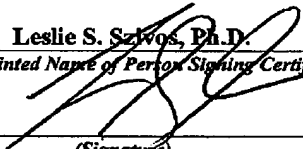
CC:**URGENT!!**

Please see the following documents:

1. Certificate of transmission by facsimile dated September 16, 2005
2. Transmittal letter (in duplicate)
3. Authorization to charge IBM deposit account
4. Response under 37 C.F.R. §§1.111 and 1.143

If you have any questions concerning this facsimile please do not hesitate to contact Vivian Henriquez at 516-742-4343. Thank you.

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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8) Applicant(s): Hussein I. Hanafi et al.			Docket No. YOR920020182US2 (15790A)	
Application No. 10/659,949	Filing Date September 11, 2003	Examiner Fernando L. Toledo	Group Art Unit 2823	
Invention: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN INNOVATIVE OXIDE REMOVAL ETCH				
<p>I hereby certify that this <u>Response under 37 C.F.R. §§1.111 AND 1.143</u> (Identify type of correspondence) is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>571-273-8300</u>) on <u>September 11, 2005</u> (Date)</p> <p style="text-align: right;"><u>Leslie S. Szivos, Ph.D.</u> (Typed or Printed Name of Person Signing Certificate)  (Signature)</p>				
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P18/REV02

**TRANSMITTAL LETTER
(General - Patent Pending)**Docket No.
YOR920020182US2 (15790A)In Re Application Of: **Hussein I. Hanafi et al.**

Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/659,949	September 11, 2003	Fernando L. Toledo	23389	2823	5877

**Title: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE
GATE PROCESS AND AN INNOVATIVE OXIDE REMOVAL ETHCH****COMMISSIONER FOR PATENTS:**

Transmitted herewith is:

Response under 37 C.F.R. §§1.111 and 1.143

in the above identified application.

- ☒ No additional fee is required.
- ☐ A check in the amount of _____ is attached.
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Signature

Dated: September 16, 2005

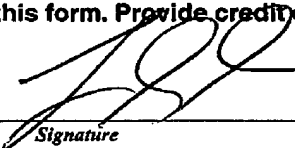
Leslie S. Szivos, Ph.D.
Reg. No. 39,394
SCULLY, SCOTT, MURPHY & PRESSER
400 Garden City Plaza - Suite 300
Garen City, New York 11530

LSS:vh

cc:

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to the "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on	
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P16A/REV03

TRANSMITTAL LETTER (General - Patent Pending)				Docket No. YOR920020182US2 (15790A)	
In Re Application Of: Hussein I. Hanafi et al.					
Application No. 10/659,949	Filing Date September 11, 2003	Examiner Fernando L. Toledo	Customer No. 23389	Group Art Unit 2823	Confirmation No. 5877
Title: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN INNOVATIVE OXIDE REMOVAL ETHCH					
<u>COMMISSIONER FOR PATENTS:</u>					
Transmitted herewith is: Response under 37 C.F.R. §§1.111 and 1.143					
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<input checked="" type="checkbox"/> No additional fee is required.					
<input type="checkbox"/> A check in the amount of _____ is attached.					
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 _____ <i>Signature</i>			Dated: September 16, 2005		
Leslie S. Szivos, Ph.D. Reg. No. 39,394 SCULLY, SCOTT, MURPHY & PRESSER 400 Garden City Plaza - Suite 300 Garden City, New York 11530					
LSS:vh CC:			<div style="border: 1px solid black; padding: 5px;"><div style="text-align: center;">_____ I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to the "Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on _____ (Date) _____ Signature of Person Mailing Correspondence _____ Typed or Printed Name of Person Mailing Correspondence</div></div>		

P16A/REV03

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SEP 16 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**Applicant(s):** Hussein I. Hanafi et al.**Examiner:** Fernando L. Toledo**Serial No:** 10/659,949**Art Unit:** 2823**Filed:** September 11, 2003**Docket:** YOR920020182US2 (15790A)**For: LOW RESISTANCE T-GATE MOSFET
DEVICE USING A DAMASCENE GATE
PROCESS AND AN INNOVATIVE OXIDE
REMOVAL ETCH****Dated:** September 16, 2005**Confirmation No.:** 5877Mail Stop Amendment
Commissioner for Patents
United States Patent Office
Alexandria, VA 23313-1450**RESPONSE UNDER 37 C.F.R. §§1.111 AND 1.143**

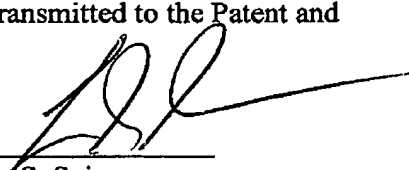
Sir:

In response to the Office Action dated August 16, 2005, applicants provisionally elect, without traverse, the subject matter of Group II, i.e., Claims 14-20 for continued prosecution in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: September 16, 2005



Leslie S. Szivos